N-Channel 150-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

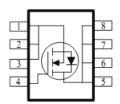
Typical Applications:

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I _D (A)	
150	255 @ V _{GS} = 10V	2.9	
	290 @ V _{GS} = 5.5V	2.7	







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Orain-Source Voltage		V_{DS}	150	V	
Gate-Source Voltage			±20	V	
O	T _A =25°C	;	2.9	А	
Continuous Drain Current a	T _A =70°C	I _D	2.4		
Pulsed Drain Current ^b			20		
Continuous Source Current (Diode Conduction) ^a		Is	4	Α	
Device Discipation a	T _A =25°C	P _D	3.1	W	
Power Dissipation ^a	T _A =70°C	FD	2.2	v v	
Operating Junction and Storage Temperature Range	_	T _J , T _{sta}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	40	°C/W		
Maximum Junction-to-Ambient	Steady State	IΛθJA	80	C/VV		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

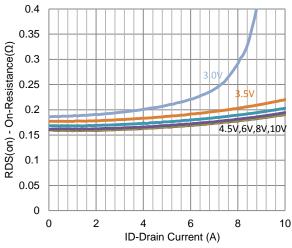
Parameter	Symbol	nbol Test Conditions		Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	uA	
Zoro Coto Voltogo Droin Current	lane	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	1.5			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_D = 2.3 \text{ A}$			255	mΩ	
Dialii-Source Ori-Nesistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 2.2 \text{ A}$			290	11122	
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 2.3 \text{ A}$		10		S	
Diode Forward Voltage	V_{SD}	$I_{S} = 2 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
		Dynamic					
Total Gate Charge	Q_g			12			
Gate-Source Charge	Q_{gs}	$V_{DS} = 75 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 2.3 \text{ A}$		3.3		nC	
Gate-Drain Charge	Q_{gd}			6.5			
Turn-On Delay Time	t _{d(on)}			10			
Rise Time	t _r	$V_{DD} = 75 \text{ V}, R_L = 32.3 \Omega, I_D = 2.3 \text{ A},$ $V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		11		ns	
Turn-Off Delay Time	$t_{d(off)}$			59			
Fall Time	t _f			23			
Input Capacitance	C _{iss}			920			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		101		pF	
Reverse Transfer Capacitance	C_{rss}	<u> </u>		77			

Notes

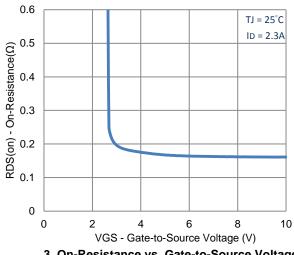
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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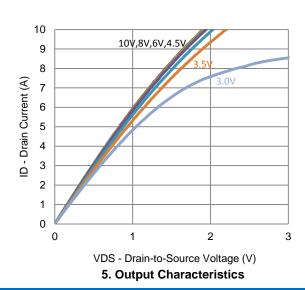
Typical Electrical Characteristics

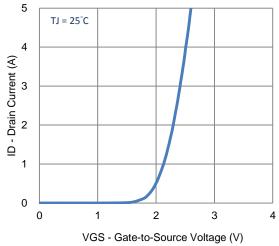


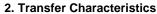
1. On-Resistance vs. Drain Current

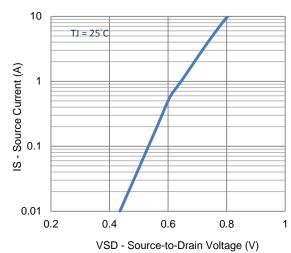


3. On-Resistance vs. Gate-to-Source Voltage

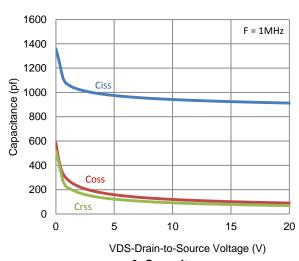






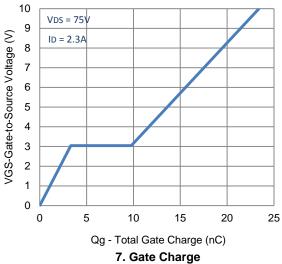


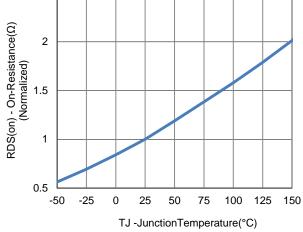
4. Drain-to-Source Forward Voltage



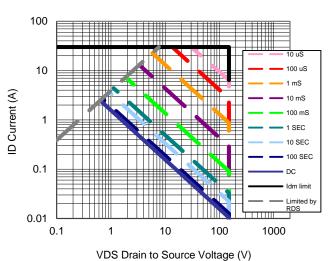
Typical Electrical Characteristics

2.5

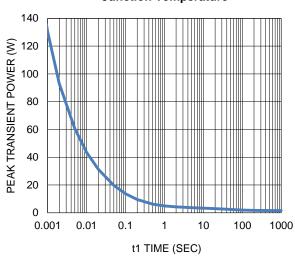




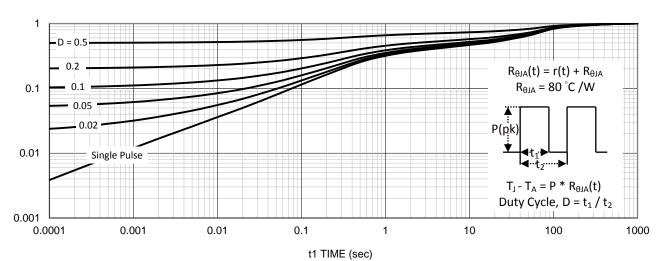
8. Normalized On-Resistance Vs **Junction Temperature**



9. Safe Operating Area



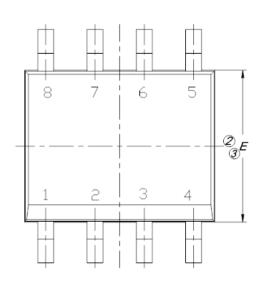
10. Single Pulse Maximum Power Dissipation

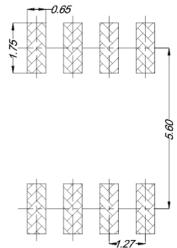


11. Normalized Thermal Transient Junction to Ambient

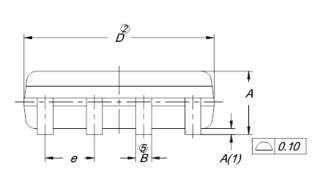
Package Information

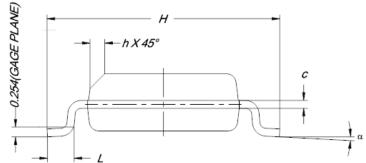
Land Pattern (Only for Reference)





DIM.	MILLIMETERS				
	MIN.	NOM.	MAX.		
Α	1.35	1.55	1.75		
A(1)	0.10	0.18	0.25		
В	0.38	0.45	0.51		
С	0.19	0.22	0.25		
D	4.80	4.90	5.00		
E	3.80	3.90	4.00		
е	1.27 BSC				
Н	5.80	6.00	6.20		
L	0.50	0.72	0.93		
α	0°	4°	8°		
h	0.25	0.38	0.50		





Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- Dimension "B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess
 Of "B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The
 Foot.

Ordering Information

AM4392N-T1-XX

A: Analog Power

- M: MOSFET

- 4392: Part number

– N: N-Channel

– T1: Tape & reel

– XX: Blank: Standard

PF: Leadfree